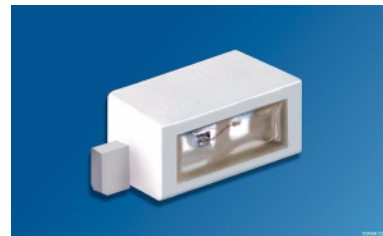


Hyper Micro SIDELED® Hyper-Bright LED

LS Y876, LA Y876, LO Y876, LY Y876



Vorläufige Daten / Preliminary Data

Besondere Merkmale

- **Gehäusetyyp:** weißes SMT-Gehäuse
- **Besonderheit des Bauteils:** kleine Bauform mit extrem breiter Abstrahlcharakteristik; ideal für Einkopplungen in Lichtleiter
- **Wellenlänge:** 633 nm (super-rot), 615 nm (amber), 606 nm (orange), 587 nm (gelb)
- **Abstrahlwinkel:** Lambertischer Strahler (120°)
- **Technologie:** InGaAIP
- **optischer Wirkungsgrad:** 9 lm/W (gelb, orange, amber), 5 lm/W (super-rot)
- **Gruppierungsparameter:** Lichtstärke, Wellenlänge
- **Verarbeitungsmethode:** für alle SMT-Bestücktechniken geeignet
- **Lötmethode:** IR Reflow Löten und Wellenlöten (TTW)
- **Vorbehandlung:** nach JEDEC Level 2
- **Gurtung:** 8 mm Gurt mit 3000/Rolle, \varnothing 180 mm oder 10000/Rolle, \varnothing 330 mm

Anwendungen

- optimale Einkopplung in Lichtleiter
- Hinterleuchtung (LCD, Mobiltelefone, Tasten, Allgemeinbeleuchtung, Werbebeleuchtung)
- Signal- und Symbolleuchten
- Automobilbereich (z. B. Instrumentenbeleuchtung)

Features

- **package:** white SMT package
- **feature of the device:** small package with extremely wide viewing angle; ideal for coupling in light guides
- **wavelength:** 633 nm (super-red), 615 nm (amber), 606 nm (orange), 587 nm (yellow)
- **viewing angle:** Lambertian Emitter (120°)
- **technology:** InGaAIP
- **optical efficiency:** 9 lm/W (yellow, orange, amber), 5 lm/W (super-red)
- **grouping parameter:** luminous intensity, wavelength
- **assembly methods:** suitable for all SMT assembly methods
- **soldering methods:** IR reflow soldering and TTW soldering
- **preconditioning:** acc. to JEDEC Level 2
- **taping:** 8 mm tape with 3000/reel, \varnothing 180 mm or 10000/reel, \varnothing 330 mm

Applications

- optimized coupling into light guides
- backlighting (LCD, cellular phones, keys, general lightning, illuminated advertising)
- signal and symbol luminaire
- automotive (e. g. car radio backlighting)

Typ	Emissions- farbe	Farbe der Lichtaustritts- fläche	Lichtstärke	Lichtstrom	Bestellnummer
Type	Color of Emission	Color of the Light Emitting Area	Luminous Intensity $I_F = 20 \text{ mA}$ $I_V \text{ (mcd)}$	Luminous Flux $I_F = 20 \text{ mA}$ $\Phi_V \text{ (mlm)}$	Ordering Code
LA Y876-Q1R1-1 LA Y876-R1S2-1	amber	colorless clear	71 ... 140 112 ... 280	300 (typ.) 560 (typ.)	Q65110A0380 Q65110A0381
LS Y876-P1Q1-1 LS Y876-Q1R2-1	super-red	colorless clear	45 ... 90 71 ... 180	200 (typ.) 370 (typ.)	Q65110A0388 Q65110A0485
LO Y876-Q2R2-24 LO Y876-R2T1-24	orange	colorless clear	90 ... 180 140 ... 355	400 (typ.) 740 (typ.)	Q65110A0403 Q65110A0483
LY Y876-Q1R1-26 LY Y876-R1S2-26	yellow	colorless clear	71 ... 140 112 ... 280	300 (typ.) 560 (typ.)	Q65110A0405 Q65110A0480

Anm.: -1 gesamter Farbbereich (siehe **Seite 4**)

-24 gesamter Farbbereich, Lieferung in Einzelgruppen (siehe **Seite 5**)

-26 gesamter Farbbereich, Lieferung in Einzelgruppen (siehe **Seite 5**)

Die Standardlieferform von Serientypen beinhaltet eine untere bzw. eine obere Familiengruppe, die aus nur 3 bzw. 4 Halbgruppen besteht. Einzelne Halbgruppen sind nicht erhältlich.
In einer Verpackungseinheit / Gurt ist immer nur eine Halbgruppe enthalten.

Note: -1 Total color tolerance range (please see **page 4**)

-24 Total color tolerance range, delivery in single groups (please see **page 5**)

-26 Total color tolerance range, delivery in single groups (please see **page 5**)

-The standard shipping format for serial types includes a lower or upper family group of 3 or 4 individual groups. Individual half groups are not available.

No packing unit / tape ever contains more than one luminous intensity half group..

Grenzwerte
Maximum Ratings

Bezeichnung Parameter	Symbol Symbol	Werte Values		Einheit Unit
		LS, LO, LA	LY	
Betriebstemperatur Operating temperature range	T_{op}	- 40 ... + 100		°C
Lagertemperatur Storage temperature range	T_{stg}	- 40 ... + 100		°C
Sperrschichttemperatur Junction temperature	T_j	+ 125		°C
Durchlassstrom Forward current	I_F	30		mA
Stoßstrom Surge current $t \leq 10 \mu s, D = 0.005$	I_{FM}	500	200	mA
Sperrspannung ¹⁾ Reverse voltage $I_F = 10 \mu A$	V_R	12		V
Leistungsaufnahme Power consumption $T_A \leq 25 \text{ °C}$	P_{tot}	80		mW
Wärmewiderstand Thermal resistance Sperrschicht/Umgebung Junction/ambient	$R_{th JA}$	630		K/W
Sperrschicht/Lötpad Junction/solder point Montage auf PC-Board FR 4 (Padgröße $\geq 5 \text{ mm}^2$) mounted on PC board FR 4 (pad size $\geq 5 \text{ mm}^2$)	$R_{th JS}$	350		K/W

¹⁾ für kurzzeitigen Betrieb geeignet / suitable for short term application

Kennwerte ($T_A = 25\text{ °C}$)

Characteristics

Bezeichnung Parameter	Symbol Symbol	Werte Values				Einheit Unit
		LS	LA	LO	LY	
Wellenlänge des emittierten Lichtes (typ.) Wavelength at peak emission $I_F = 20\text{ mA}$	λ_{peak}	645	622	610	591	nm
Dominantwellenlänge ¹⁾ (typ.) Dominant wavelength ¹⁾ $I_F = 20\text{ mA}$	λ_{dom}	633 ± 6	615 ± 6	606 -6/+3	587 -7/+8	nm
Spektrale Bandbreite bei 50 % $I_{\text{rel max}}$ (typ.) Spectral bandwidth at 50 % $I_{\text{rel max}}$ $I_F = 20\text{ mA}$	$\Delta\lambda$	16	16	16	15	nm
Abstrahlwinkel bei 50 % I_V (Vollwinkel) (typ.) Viewing angle at 50 % I_V	2ϕ	120	120	120	120	Grad deg.
Durchlassspannung ²⁾ (typ.) Forward voltage ²⁾ (max.) $I_F = 20\text{ mA}$	V_F V_F	2.0 2.4	2.0 2.4	2.0 2.4	2.0 2.4	V V
Sperrstrom (typ.) Reverse current (max.) $V_R = 12\text{ V}$	I_R I_R	0.01 10	0.01 10	0.01 10	0.01 10	μA μA
Temperaturkoeffizient von λ_{peak} (typ.) Temperature coefficient of λ_{peak} $I_F = 20\text{ mA}; -10\text{ °C} \leq T \leq 100\text{ °C}$	$TC_{\lambda_{\text{peak}}}$	0.14	0.13	0.13	0.13	nm/K
Temperaturkoeffizient von λ_{dom} (typ.) Temperature coefficient of λ_{dom} $I_F = 20\text{ mA}; -10\text{ °C} \leq T \leq 100\text{ °C}$	$TC_{\lambda_{\text{dom}}}$	0.05	0.06	0.07	0.10	nm/K
Temperaturkoeffizient von V_F (typ.) Temperature coefficient of V_F $I_F = 20\text{ mA}; -10\text{ °C} \leq T \leq 100\text{ °C}$	TC_V	-2.0	-1.8	-1.7	-2.5	mV/K
Optischer Wirkungsgrad (typ.) Optical efficiency $I_F = 20\text{ mA}$	η_{opt}	5	9	9	9	lm/W

¹⁾ Wellenlängen werden mit einer Stromeinprägedauer von 25 ms und einer Genauigkeit von $\pm 1\text{ nm}$ ermittelt.
Wavelengths are tested at a current pulse duration of 25 ms and a tolerance of $\pm 1\text{ nm}$.

²⁾ Spannungswerte werden mit einer Stromeinprägedauer von 1 ms und einer Genauigkeit von $\pm 0,1\text{ V}$ ermittelt.
Voltages are tested at a current pulse duration of 1 ms and a tolerance of $\pm 0.1\text{ V}$.

¹⁾ Wellenlängengruppen / Wavelength groups

Gruppe Group	yellow		orange		Einheit Unit
	min.	max.	min.	max.	
2	580	583	600	603	nm
3	583	586	603	606	nm
4	586	589	606	609	nm
5	589	592			nm
6	592	595			nm

Helligkeitswerte werden mit einer Stromeinprägedauer von 25 ms und einer Genauigkeit von ±11 % ermittelt.
Luminous intensity is tested at a current pulse duration of 25 ms and a tolerance of ±11 %.

Helligkeits-Gruppierungsschema
Luminous Intensity Groups

Lichtgruppe Luminous Intensity Group	Lichtstärke Luminous Intensity I_V (mcd)	Lichtstrom Luminous Flux Φ_V (lm)
P1	45 ... 56	150 (typ.)
P2	56 ... 71	190 (typ.)
Q1	71 ... 90	240 (typ.)
Q2	90 ... 112	300 (typ.)
R1	112 ... 140	380 (typ.)
R2	140 ... 180	480 (typ.)
S1	180 ... 224	600 (typ.)
S2	224 ... 280	720 (typ.)
T1	280 ... 355	900 (typ.)

Helligkeitswerte werden mit einer Stromeinprägedauer von 25 ms und einer Genauigkeit von ±11 % ermittelt.
Luminous intensity is tested at a current pulse duration of 25 ms and a tolerance of ±11 %.

Gruppenbezeichnung auf Etikett
Group Name on Label

Beispiel: S1-3

Example: S1-3

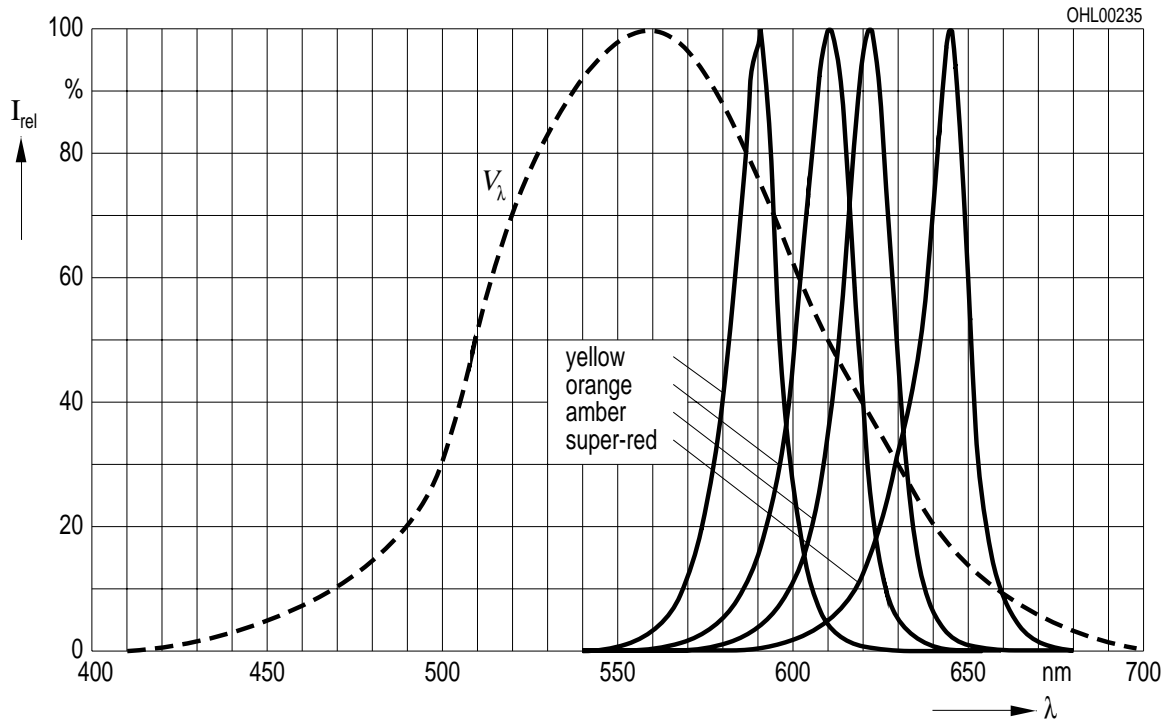
Lichtgruppe Luminous Intensity Group	Halbgruppe Half Group	Wellenlänge Wavelength
S	1	3

Relative spektrale Emission $I_{rel} = f(\lambda)$, $T_A = 25\text{ °C}$, $I_F = 20\text{ mA}$

Relative Spectral Emission

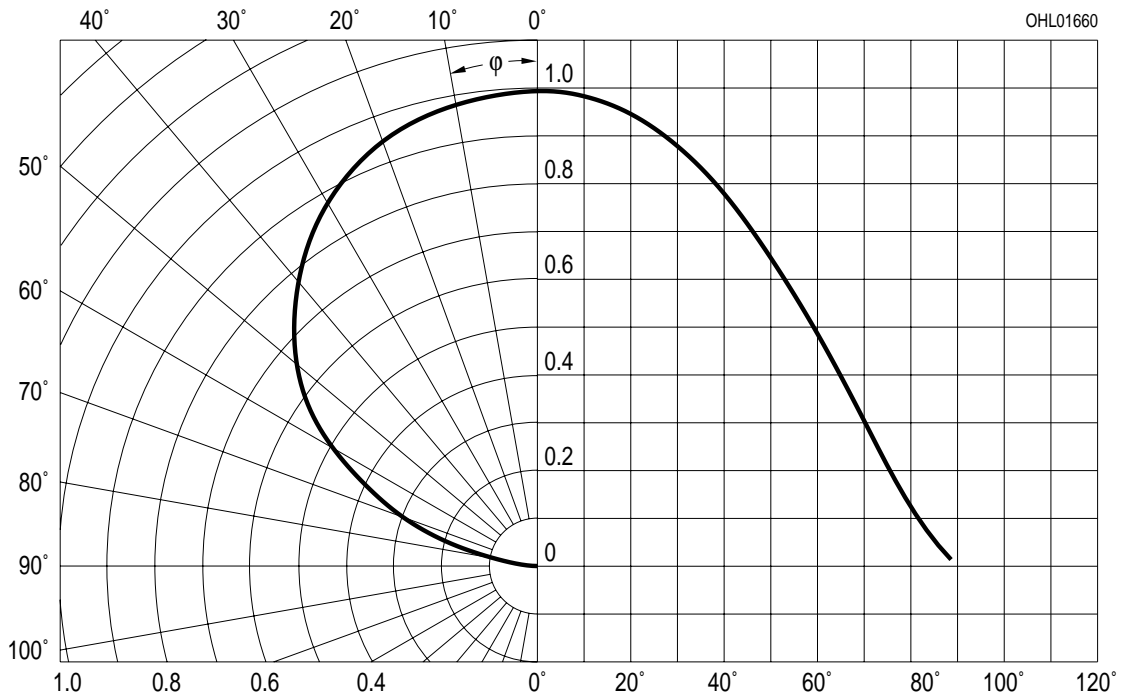
$V(\lambda)$ = spektrale Augenempfindlichkeit

Standard eye response curve



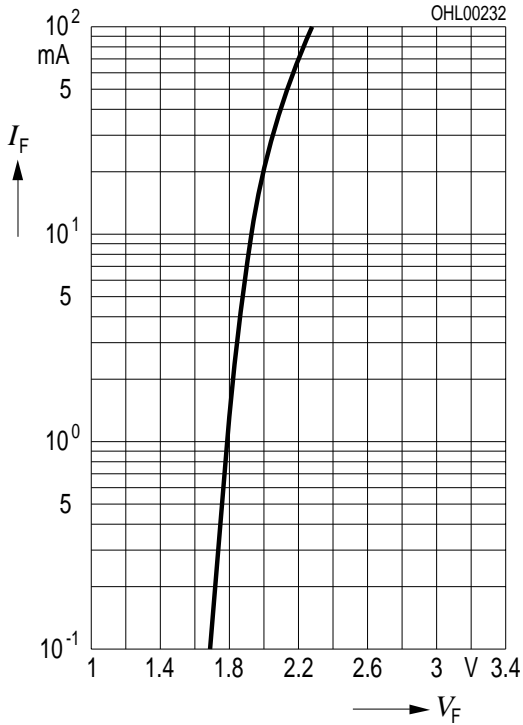
Abstrahlcharakteristik $I_{rel} = f(\varphi)$

Radiation Characteristic



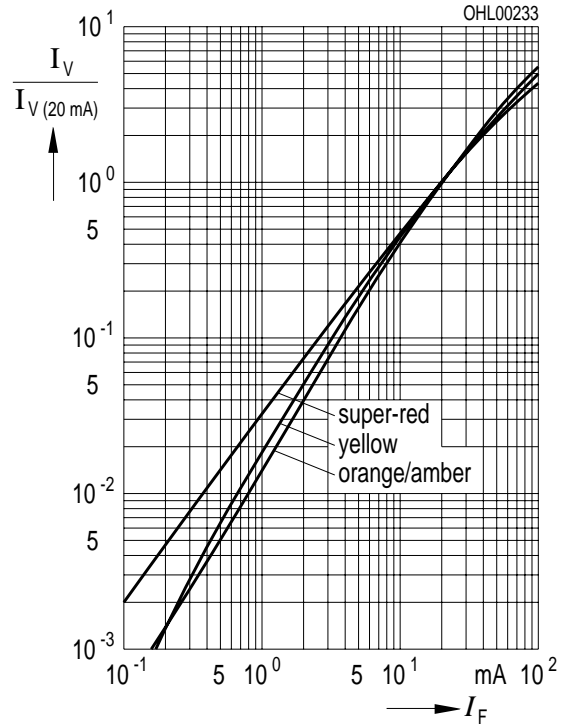
Durchlassstrom $I_F = f(V_F)$
Forward Current

$T_A = 25\text{ °C}$

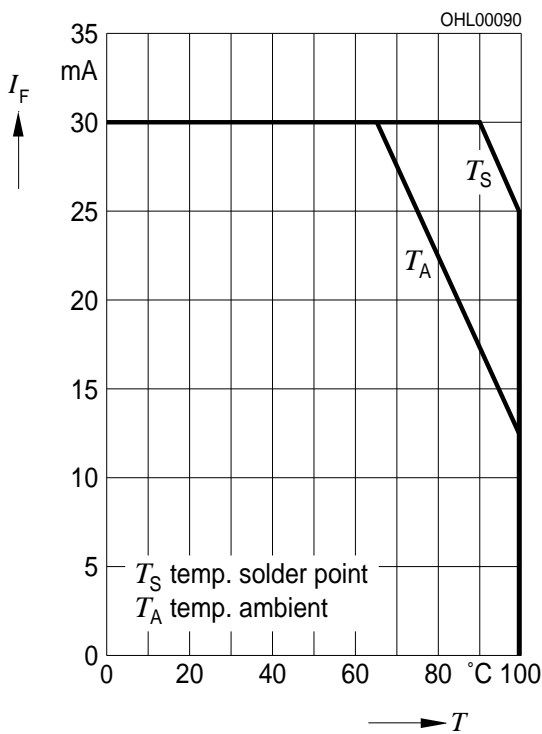


Relative Lichtstärke $I_V/I_{V(20\text{ mA})} = f(I_F)$
Relative Luminous Intensity

$T_A = 25\text{ °C}$

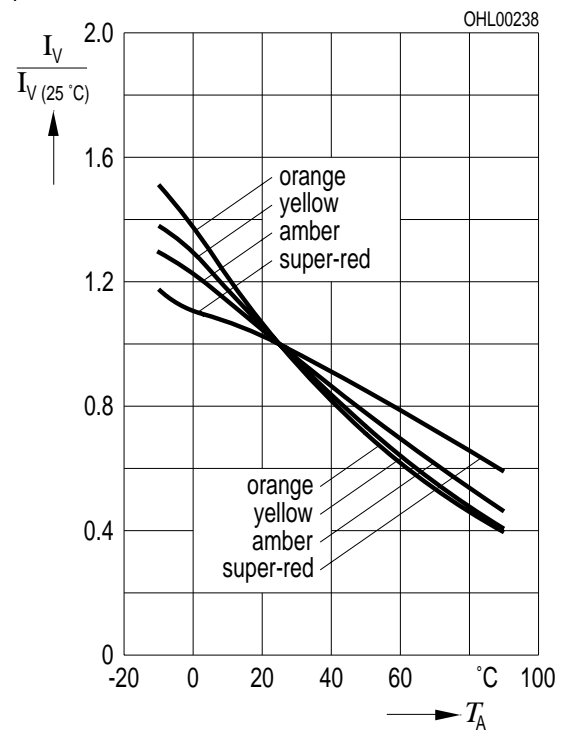


Maximal zulässiger Durchlassstrom $I_F = f(T)$
Max. Permissible Forward Current

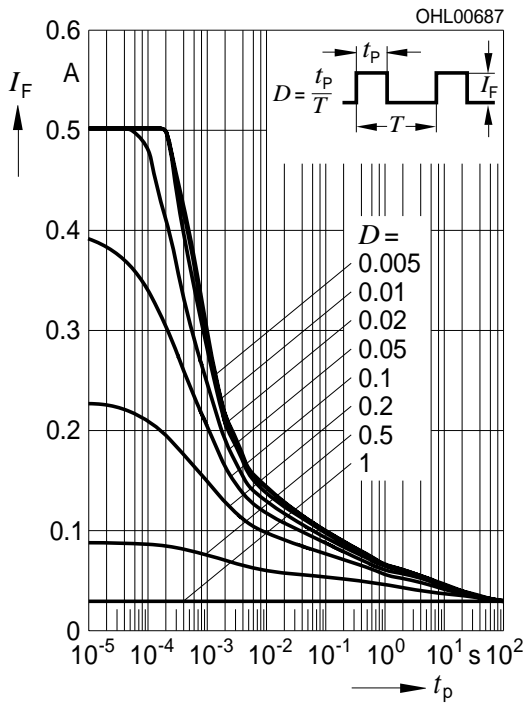


Relative Lichtstärke $I_V/I_{V(25\text{ °C})} = f(T_A)$
Relative Luminous Intensity

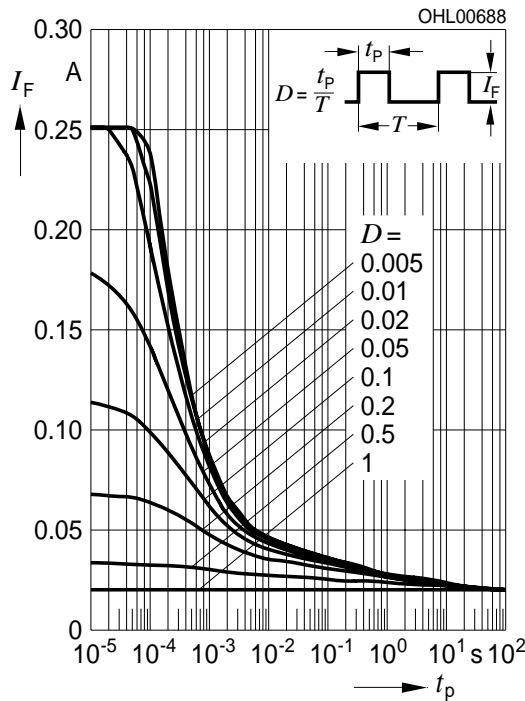
$I_F = 20\text{ mA}$



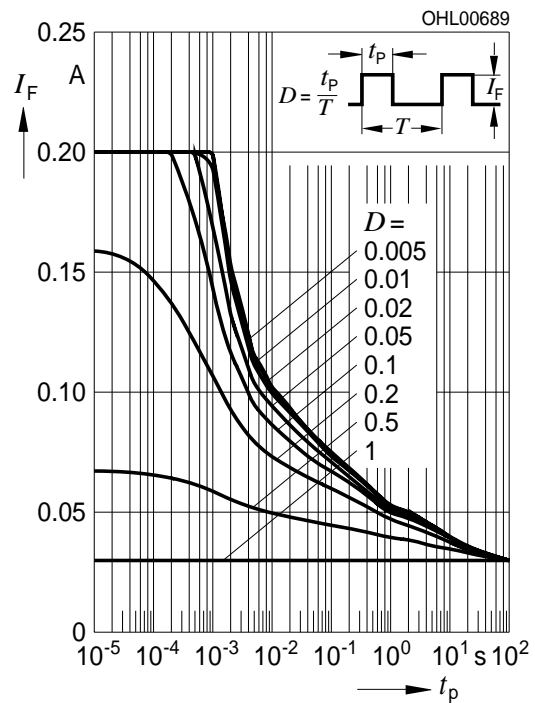
Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
 Duty cycle $D =$ parameter, $T_A = 25\text{ °C}$
LS, LA, LO



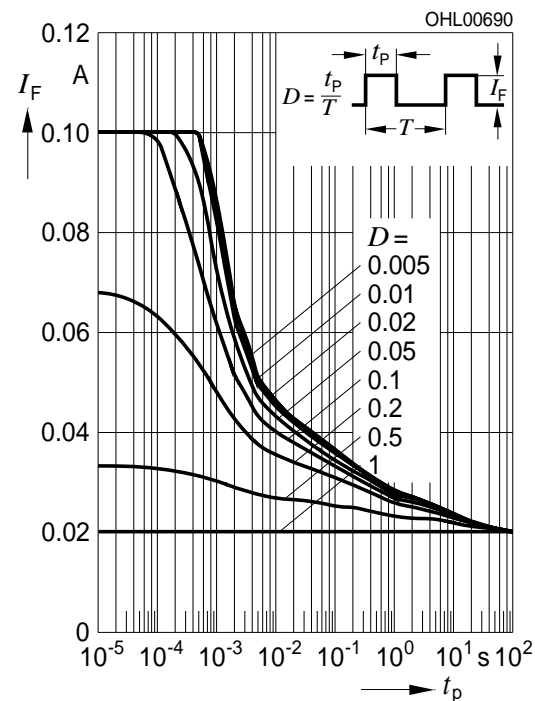
Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
 Duty cycle $D =$ parameter, $T_A = 85\text{ °C}$
LS, LA, LO



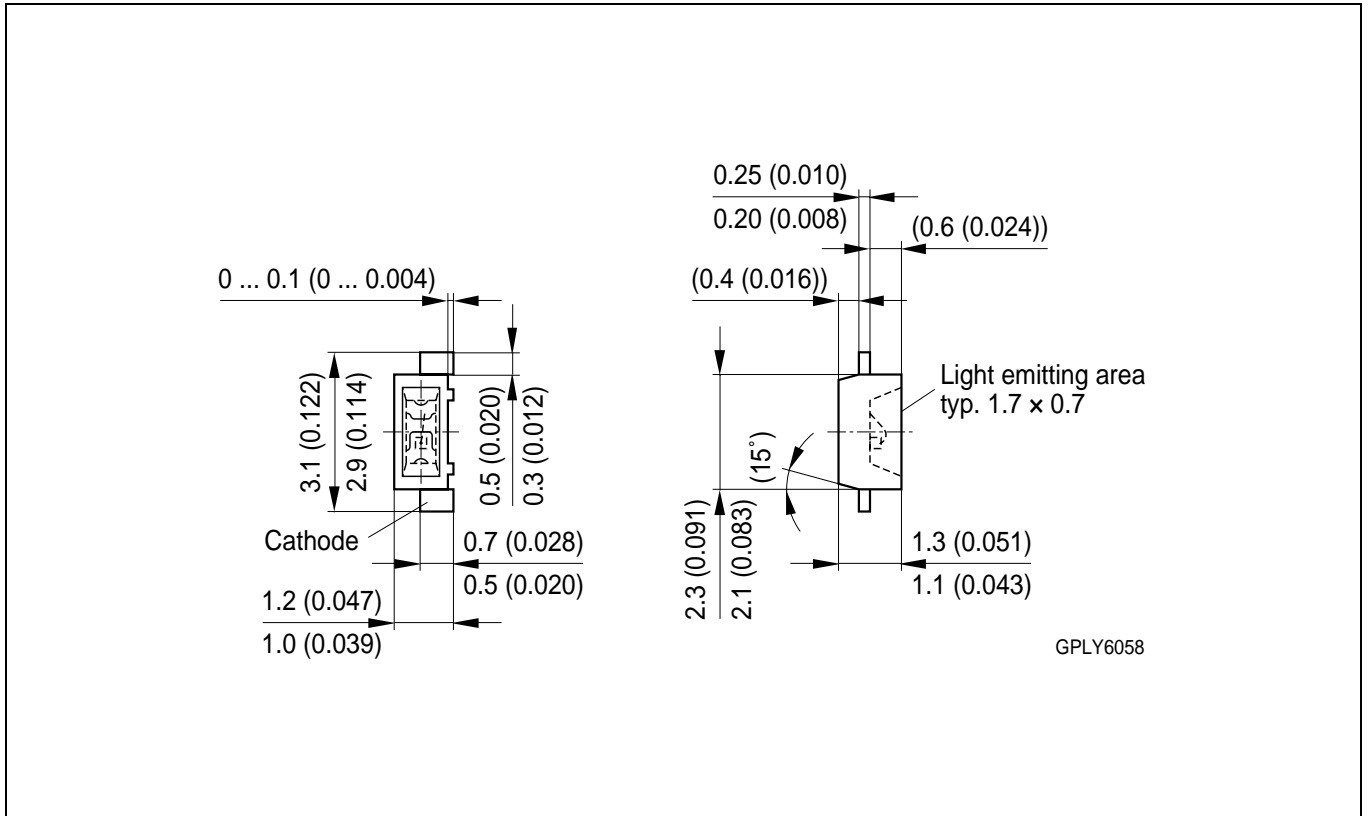
Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
 Duty cycle $D =$ parameter, $T_A = 25\text{ °C}$
LY



Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
 Duty cycle $D =$ parameter, $T_A = 85\text{ °C}$
LY



Maßzeichnung
Package Outlines

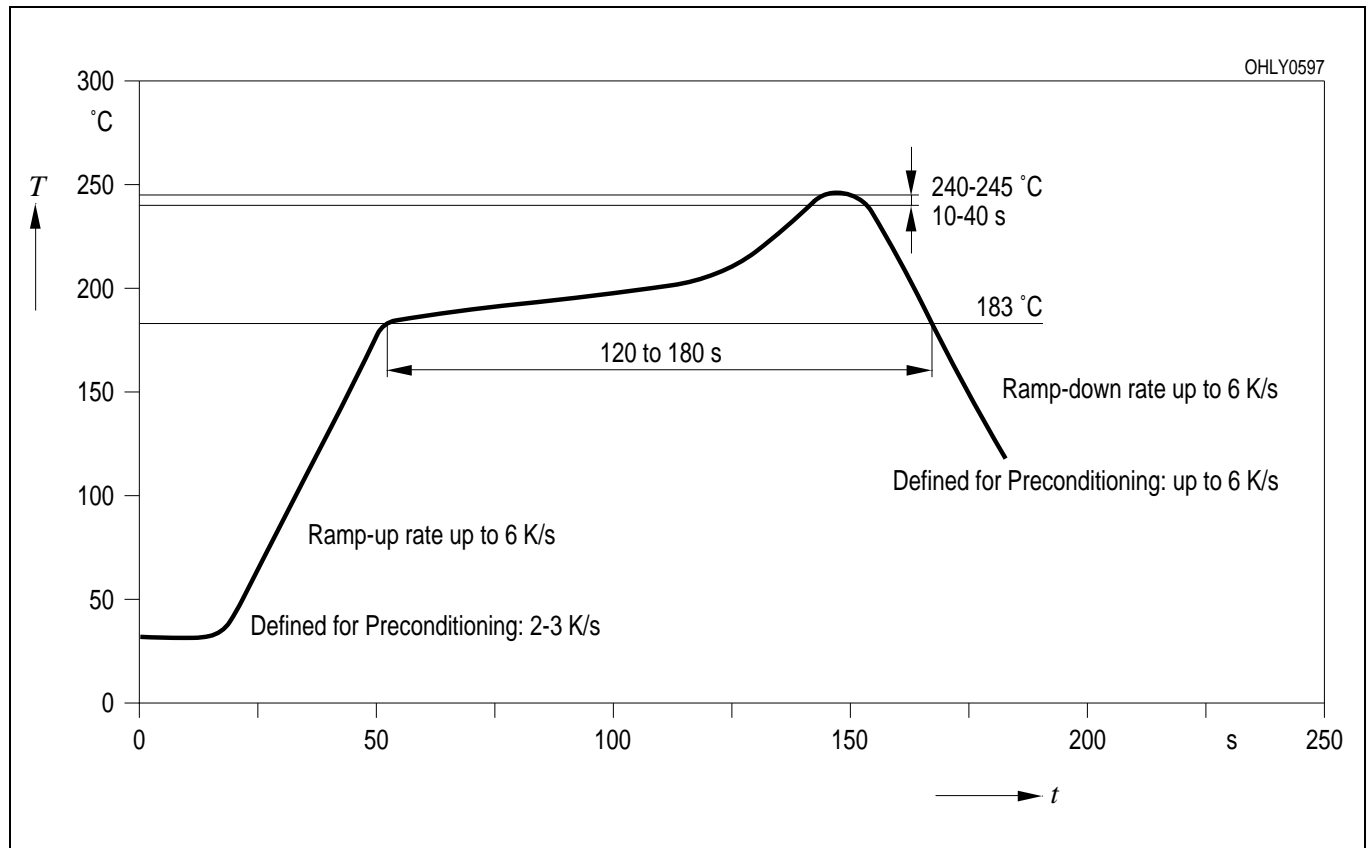


Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

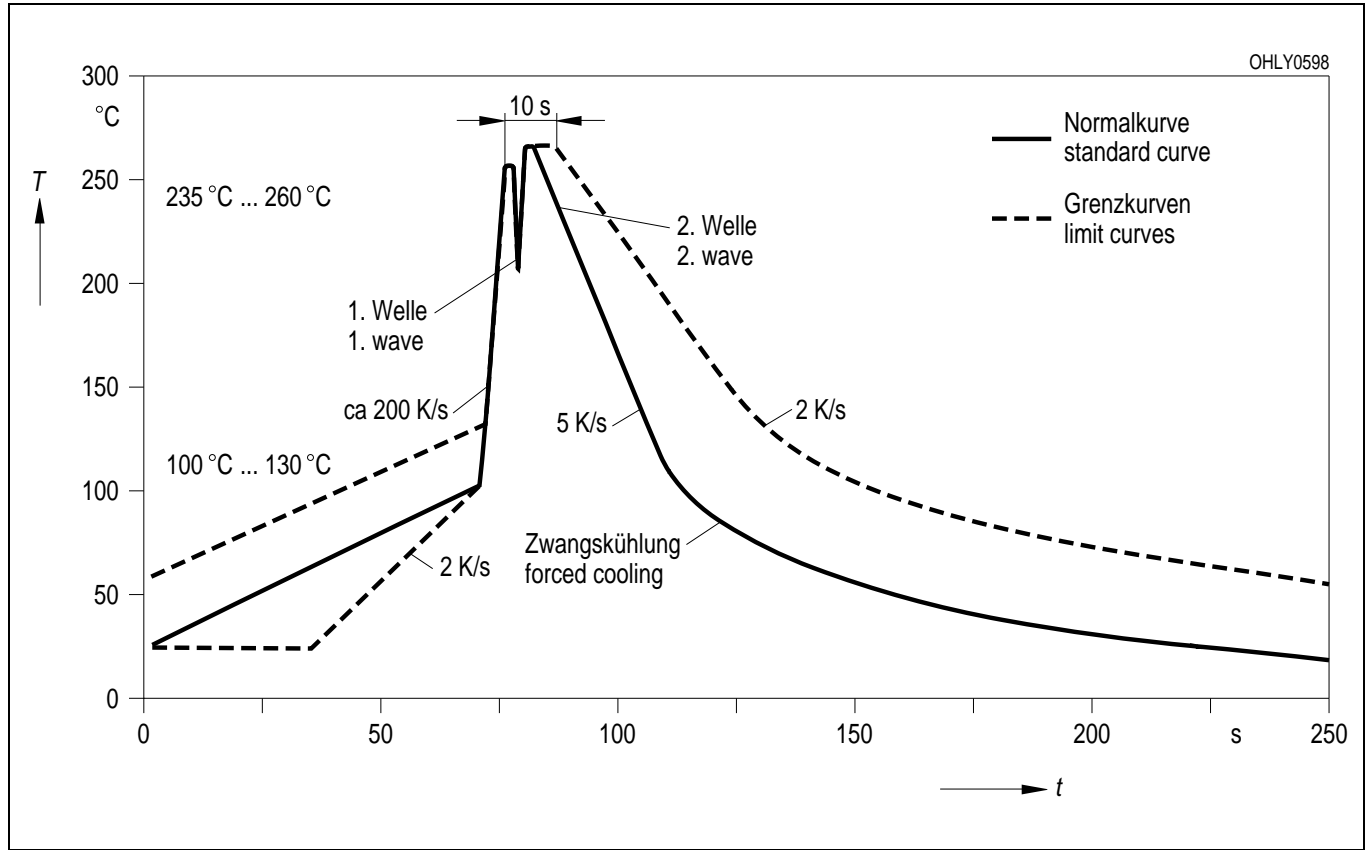
Gewicht / Approx. weight: 6 mg

Lötbedingungen Vorbehandlung nach JEDEC Level 2
Soldering Conditions Preconditioning acc. to JEDEC Level 2

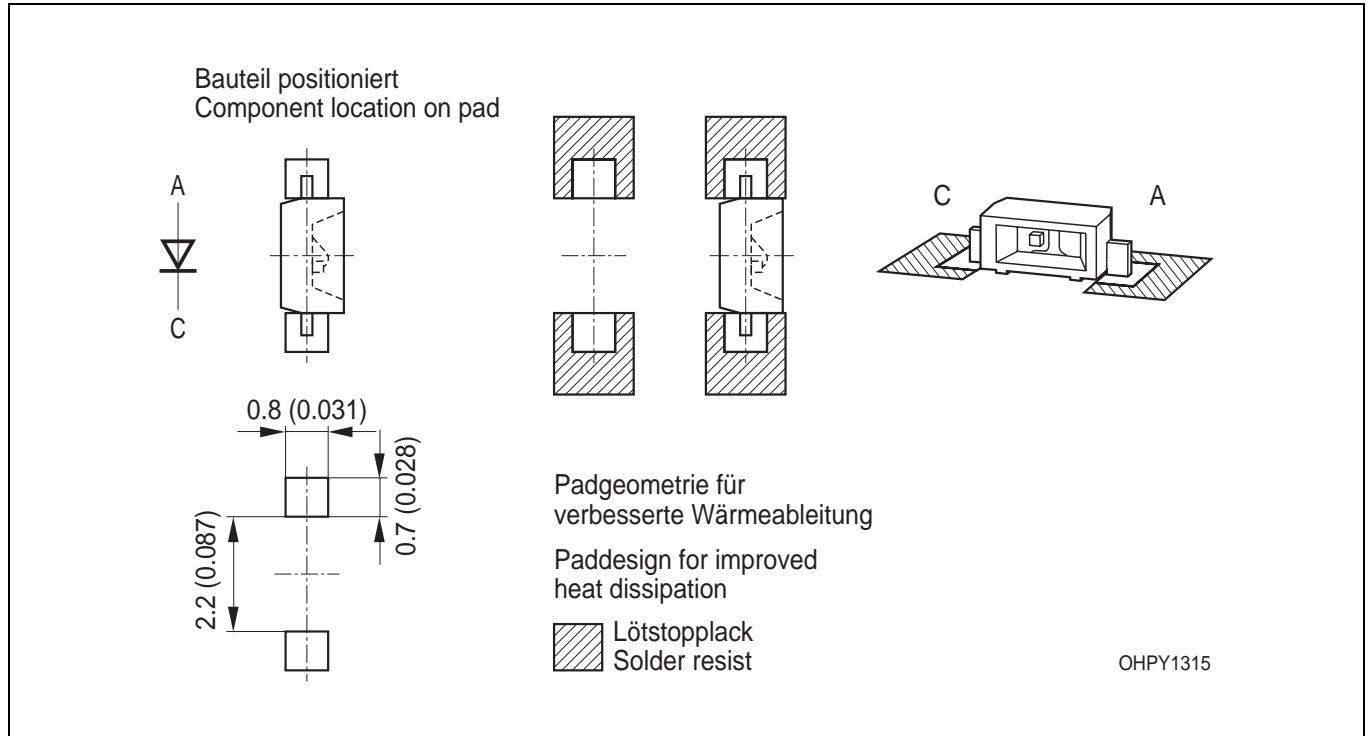
IR-Reflow Lötprofil (nach IPC 9501)
IR Reflow Soldering Profile (acc. to IPC 9501)



Wellenlöten (TTW) (nach CECC 00802)
TTW Soldering (acc. to CECC 00802)



Empfohlenes Lötpaddesign IR Reflow Löten
Recommended Solder Pad IR Reflow Soldering



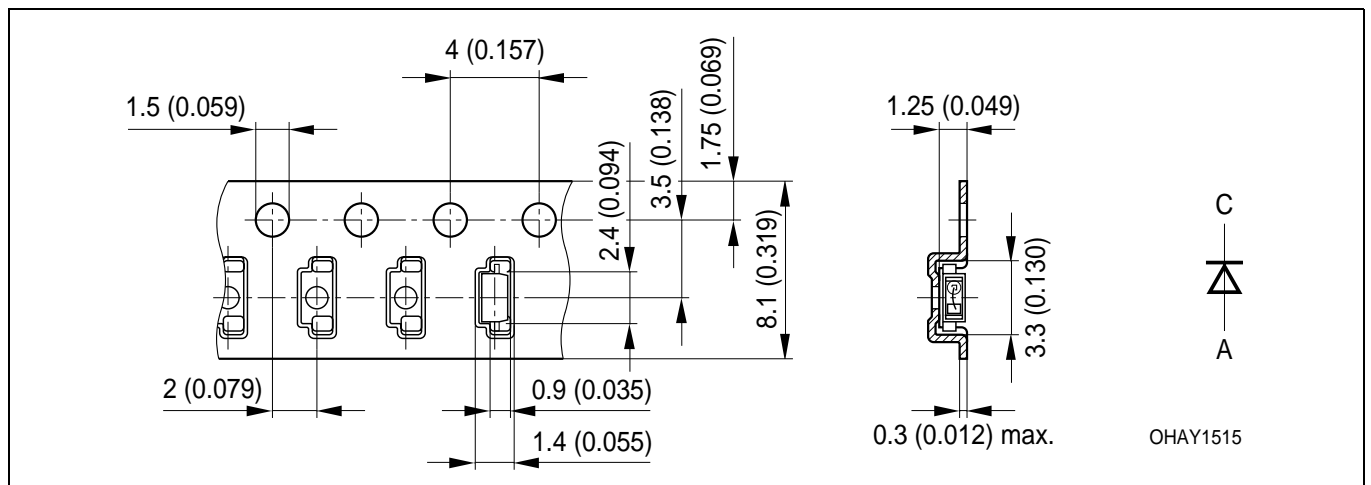
Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).
 Gehäuse hält TTW-Löthitze aus / Package able to withstand TTW-soldering heat

Gurtung / Polarität und Lage

Verpackungseinheit 3000/Rolle, ø180 mm
 oder 10000/Rolle, ø330 mm

Method of Taping / Polarity and Orientation

Packing unit 3000/reel, ø180 mm
 or 10000/reel, ø330 mm



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

Revision History: 2002-10-18		Date of change
Previous Version: 2002-10-09		
Page	Subjects (major changes since last revision)	
5	wavelength groups	
2	wavelength grouping for yellow and orange	
3	pad size from 16 mm ² to 5 mm ²	
3 / 8	Surge current	
13	annotations	2002-07-25
4	value ($TC_{\lambda,dom}$ from 0.01 to 0.05 nm/K)	2002-07-25
3, 4	value (reverse voltage from 3 V to 12 V)	2002-09-18
2, 5	new Q-numbers and new luminous intensity groups (all colours)	2002-10-09

Published by OSRAM Opto Semiconductors GmbH

Wernerwerkstrasse 2, D-93049 Regensburg

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Attention please!

The information describes the type of component and shall not be considered as assured characteristics.

All typical data and graphs are basing on representative samples, but don't represent the production range. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.

Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances. For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version in the Internet.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Components used in life-support devices or systems must be expressly authorized for such purpose! Critical components ¹ may only be used in life-support devices or systems ² with the express written approval of OSRAM OS.

¹ A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or the effectiveness of that device or system.

² Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health of the user may be endangered.